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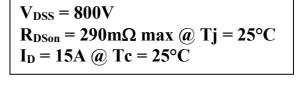


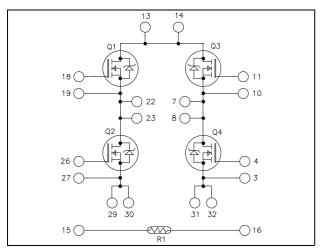






### Full - Bridge Super Junction MOSFET Power Module





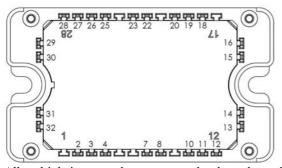
#### **Application**

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

#### **Features**

#### • Super junction MOSFET

- Ultra low R<sub>DSon</sub>
- Low Miller capacitance
- Ultra low gate charge
- Avalanche energy rated
- Very rugged
- Kelvin source for easy drive
- Very low stray inductance
- Internal thermistor for temperature monitoring



All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23...

#### **Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability
- RoHS Compliant

### All ratings (a) $T_i = 25^{\circ}C$ unless otherwise specified

#### Absolute maximum ratings (per super junction MOSFET)

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Voltage		800	V
Ţ		$T_c = 25^{\circ}C$	15	
$I_D$	Continuous Drain Current $T_c = 80^{\circ}$		11	A
$I_{DM}$	Pulsed Drain current		60	
$V_{GS}$	Gate - Source Voltage		±30	V
$R_{DSon}$	Drain - Source ON Resistance		290	mΩ
$P_D$	Power Dissipation $T_c = 25$ °C		156	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)		17	A
$E_{AR}$	Repetitive Avalanche Energy		0.5	T
Eas	Single Pulse Avalanche Energy		670	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

### **Electrical Characteristics** (per super junction MOSFET)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 800V$			25	μA
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 7.5A$			290	$m\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 1 \text{mA}$	2.1	3	3.9	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

### **Dynamic Characteristics** (per super junction MOSFET)

·	Characteristic	Test Conditions	Min	Тур	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		2254		
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		1046		pF
$C_{rss}$	Reverse Transfer Capacitance	f = 1MHz		54		
$Q_{\mathrm{g}}$	Total gate Charge	$V_{GS} = 10V$		90		
$Q_{gs}$	Gate – Source Charge	$V_{Bus} = 400V$		11		пC
$Q_{\mathrm{gd}}$	Gate – Drain Charge	$I_D = 15A$		45		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @125°C		10		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$		13		
$T_{d(off)}$	Turn-off Delay Time	$\begin{aligned} V_{Bus} &= 533V \\ I_D &= 15A \\ R_G &= 5\Omega \end{aligned}$		83		ns
$T_{\mathrm{f}}$	Fall Time			35		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		243		т
$E_{\text{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 533V$ $I_D = 15A, R_G = 5\Omega$		139		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		425		т
E <sub>off</sub>	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 533V$ $I_D = 15A, R_G = 5\Omega$		171		μJ
$R_{thJC}$	Junction to Case Thermal Resistance	<del>)</del>			0.80	°C/W

### Source - Drain diode ratings and characteristics (per super junction MOSFET)

Source Prairie arous rusings what enactures (per super June Men 11 certain)							
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Ţ	Continuous Source current		$Tc = 25^{\circ}C$		15		۸
$I_{S}$	(Body diode)		$Tc = 80^{\circ}C$		11		Α
$V_{SD}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -15A$	<u>.</u>			1.2	V
dv/dt	Peak Diode Recovery •					6	V/ns
$t_{rr}$	Reverse Recovery Time	$I_S = -15A$ ; $V_R = 400$	)V		550		ns
$Q_{rr}$	Reverse Recovery Charge	$di_S/dt = 100A/\mu s$			15		μC

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

 $I_S \leq \text{--} 15 A \qquad di/dt \leq 100 A/\mu s \qquad V_R \leq V_{DSS} \qquad T_j \leq 150 ^{\circ} C$ 



### Thermal and package characteristics

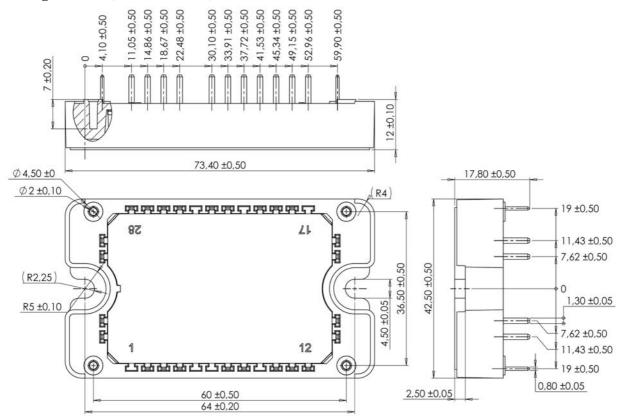
Symbol	Characteristic			Min	Max	Unit
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000		V
$T_{\rm J}$	Operating junction temperature range			-40	150	
$T_{\text{JOP}}$	Recommended junction temperature under switching conditions			-40	T <sub>J</sub> max -25	°C
$T_{STG}$	Storage Temperature Range			-40	125	C
$T_{\rm C}$	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight			110	g	

### Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic		Min	Typ	Max	Unit
R <sub>25</sub>	Resistance @ 25°C	5°C		50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta B/B$		T <sub>C</sub> =100°C		4		%

$$R_{T} = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature} \\ R_{T}: \text{ Thermistor value at T}$$

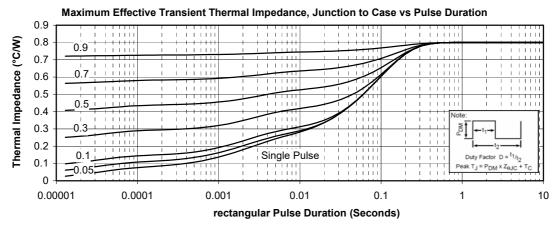
### Package outline (dimensions in mm)

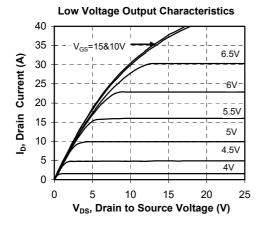


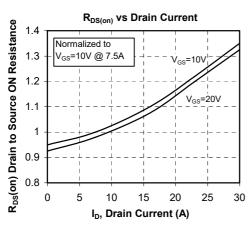
 $See \ application \ note \ 1906 - Mounting \ Instructions \ for \ SP3F \ Power \ Modules \ on \ www.microsemi.com$ 

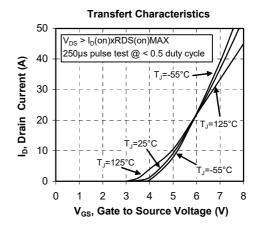


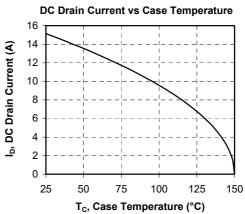
### **Typical performance Curve**



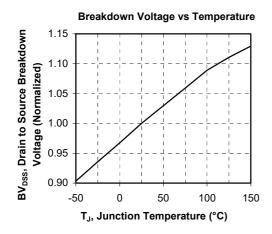


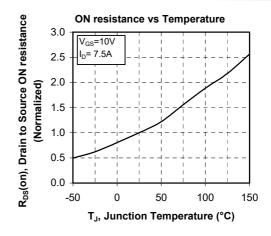


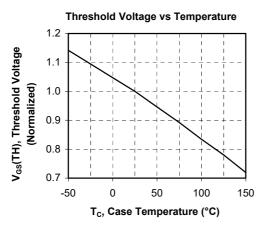


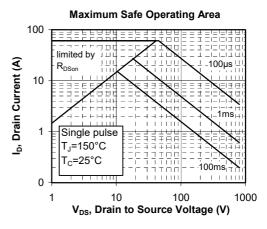


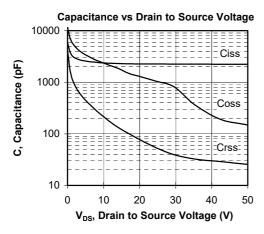


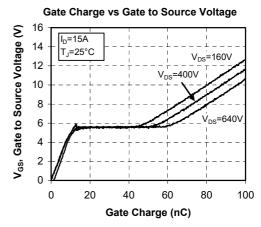




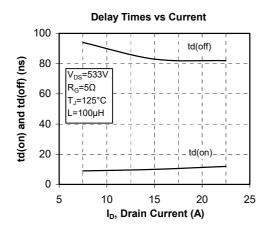


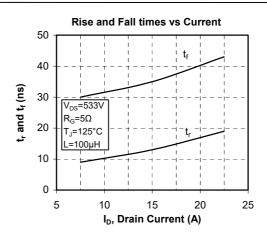


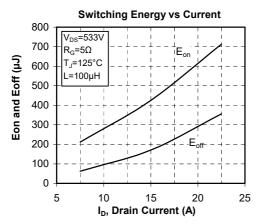


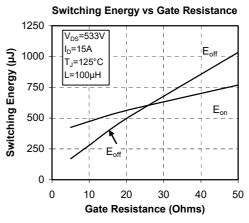


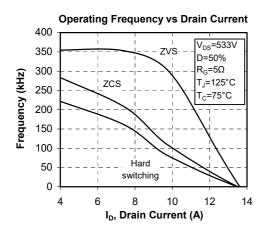


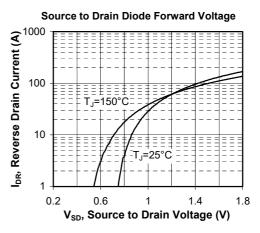












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